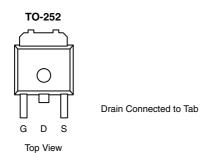


PRODUCT SUMMARY					
V <sub>DS</sub> (V)	$r_{DS(on)}(\Omega)$	I <sub>D</sub> (A) <sup>a, e</sup>	Q <sub>g</sub> (Typ)		
25	0.0086 @ V <sub>GS</sub> = 10 V	62	18.5 nC		
	0.012 @ V <sub>GS</sub> = 4.5 V	52	10.5 110		



Ordering Information: SUD50N025-09BP—E3 (Lead (Pb)-free)

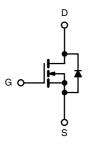
#### **FEATURES**

- TrenchFET® Power MOSFET
- 100% R<sub>g</sub> Tested
- RoHS Compliant

# Available RoHS COMPLIANT

#### **APPLICATIONS**

- DC/DC Conversion, High-Side
  - Desktop PC



N-Channel MOSFET

Parameter  Drain-Source Voltage Gate-Source Voltage		Symbol	Limit	Unit
		V <sub>DS</sub>	25	v
		$V_{GS}$	±20	
Continuous Drain Current (T <sub>J</sub> = 175°C)	T <sub>C</sub> = 25°C		62 <sup>e</sup>	
	T <sub>C</sub> = 70°C		51 <sup>e</sup>	
	T <sub>A</sub> = 25°C	I <sub>D</sub>	26 <sup>b, c</sup>	
	T <sub>A</sub> = 70°C		22 <sup>b, c</sup>	
Pulsed Drain Current		I <sub>DM</sub>	100	Α
Continuous Source-Drain Diode Current	T <sub>C</sub> = 25°C		37	
	T <sub>A</sub> = 25°C	I <sub>S</sub>	6.7 <sup>b, c</sup>	
Avalanche Current Pulse	1 04 11	I <sub>AS</sub>	28	
Single Pulse Avalanche Energy	L = 0.1 mH	E <sub>AS</sub>	39.2	mJ
Maximum Power Dissipation	T <sub>C</sub> = 25°C		55	
	T <sub>C</sub> = 70°C		39	,,,,
	T <sub>A</sub> = 25°C	P <sub>D</sub>	10 <sup>b, c</sup>	W
	T <sub>A</sub> = 70°C		7 <sup>b, c</sup>	
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>sta</sub>	-55 to 175	°C

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Typical	Maximum	Unit	
Maximum Junction-to-Ambient <sup>b, d</sup>	t ≤ 10 sec	R <sub>thJA</sub>	12	15	°C/W	
Maximum Junction-to-Case	Steady State	R <sub>thJC</sub>	2.2	2.7	*C/W	

#### Notes:

- a. Based on  $T_C = 25^{\circ}C$ .
- o. Surface mounted on 1" x 1" FR4 board.
- c. t = 10 sec
- d. Maximum under steady state conditions is 50 °C/W.
- e. Calculated based on maximum junction temperature. Package limitation current is 50 A.



Parameter	Symbol	Test Condition	Min	Тур	Max	Unit	
Static			•	•			
Drain-Source Breakdown Voltage	V <sub>DS</sub>	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$	25			٧	
V <sub>DS</sub> Temperature Coefficient	$\Delta V_{DS}/T_{J}$			20		1	
V <sub>GS(th)</sub> Temperature Coefficient	$\Delta V_{GS(th)}/T_J$	I <sub>D</sub> = 250 μA		- 6.3		mV/°C	
Gate-Source Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_D = 250 \mu A$	1.2		2.4	V	
Gate-Source Leakage	I <sub>GSS</sub>	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			±100	nA	
Zero Gate Voltage Drain Current		V <sub>DS</sub> = 25 V, V <sub>GS</sub> = 0 V	1				
	I <sub>DSS</sub>	V <sub>DS</sub> = 25 V, V <sub>GS</sub> = 0 V, T <sub>J</sub> = 55°C			10	μΑ	
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS} \ge 5 \text{ V}, V_{GS} = 10 \text{ V}$	100			А	
Drain-Source On-State Resistance <sup>a</sup>	Face .	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 26 A		0.007	0.0086	Ω	
	r <sub>DS(on)</sub>	$V_{GS} = 4.5 \text{ V}, I_D = 22 \text{ A}$		0.0096	0.012	52	
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	V <sub>DS</sub> = 15 V, I <sub>D</sub> = 26 A		46		S	
Dynamic <sup>b</sup>							
Input Capacitance	C <sub>iss</sub>			2020		pF	
Output Capacitance	C <sub>oss</sub>	$V_{DS}$ = 12 V, $V_{GS}$ = 0 V, f = 1 MHz		485			
Reverse Transfer Capacitance	C <sub>rss</sub>			245			
Total Gate Charge		V <sub>DS</sub> = 12 V, V <sub>GS</sub> = 10 V, I <sub>D</sub> = 26 A		38	57	nC	
	Qg	, 40 , 5		18.5	28		
Gate-Source Charge	$Q_{gs}$	$V_{DS} = 12 \text{ V}, \ V_{GS} = 4.5 \text{ V}, \ I_{D} = 26 \text{ A}$		7			
Gate-Drain Charge	Q <sub>gd</sub>			6.5			
Gate Resistance	Rg	f = 1 MHz		0.9	1.4	Ω	
Turn-On Delay Time	t <sub>d(on)</sub>			9	14		
Rise Time	t <sub>r</sub>	$V_{DD} = 12 \text{ V}, R_L = 0.54 \Omega$		8	12		
Turn-Off Delay Time	t <sub>d(off)</sub>	$I_D \cong 22 \text{ A}, V_{GEN} = 10 \text{ V}, R_g = 1 \Omega$		20	30		
Fall Time	t <sub>f</sub>			8	12		
Turn-On Delay Time	t <sub>d(on)</sub>			17	26	ns	
Rise Time	t <sub>r</sub>	$V_{DD} = 12 \text{ V}, R_L = 0.54 \Omega$		15	23		
Turn-Off Delay Time	t <sub>d(off)</sub>	$I_D \cong 22 \text{ A}, V_{GEN} = 4.5 \text{ V}, R_g = 1 \Omega$		17	26		
Fall Time	t <sub>f</sub>			8	12		
Drain-Source Body Diode Characte	eristics						
Continuous Source-Drain Diode Current	I <sub>S</sub>	T <sub>C</sub> = 25°C			37		
Pulse Diode Forward Current <sup>a</sup>	I <sub>SM</sub>				100	Α	
Body Diode Voltage	$V_{SD}$	I <sub>S</sub> = 6.7 A		0.9	1.5	V	
Body Diode Reverse Recovery Time	t <sub>rr</sub>			26	40	ns	
Body Diode Reverse Recovery Charge	Q <sub>rr</sub>	I <sub>F</sub> = 6.7 A, di/dt = 100 A/μs, T <sub>J</sub> = 25°C		16	24	nC	
Reverse Recovery Fall Time	ta			12			
Reverse Recovery Rise Time	t <sub>b</sub>			14		ns	

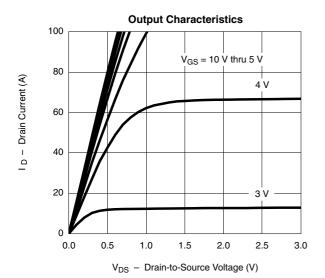
#### Notes

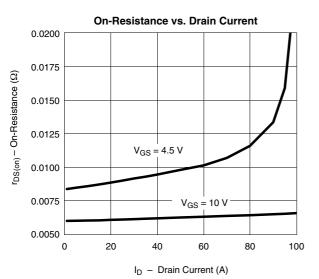
- a. Pulse test; pulse width  $\leq 300 \, \mu \text{s}$ , duty cycle  $\leq 2\%$ .
- b. Guaranteed by design, not subject to production testing.

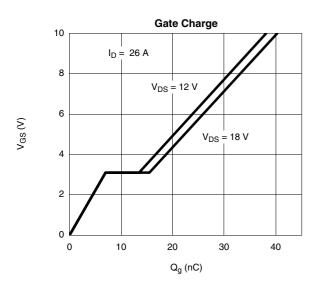
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

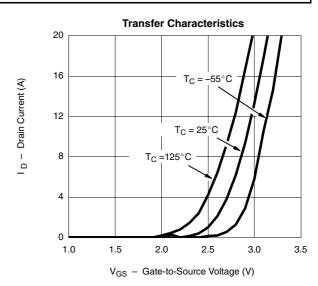


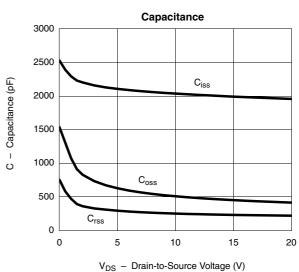
#### TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)

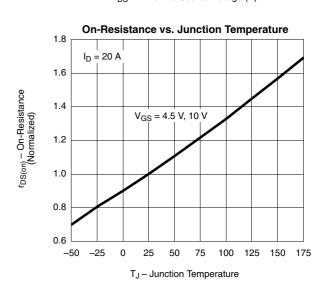






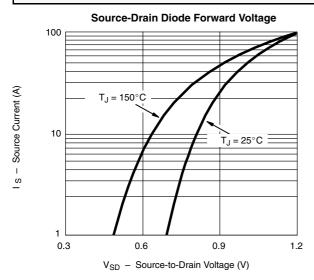


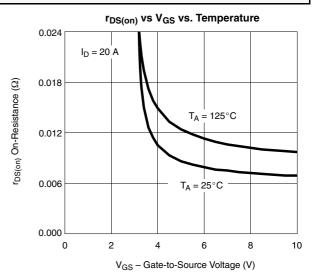


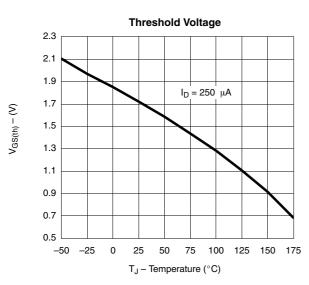


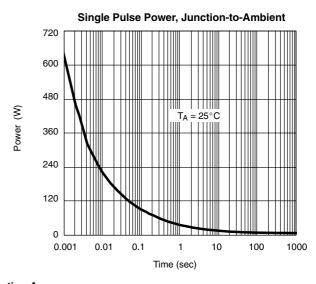


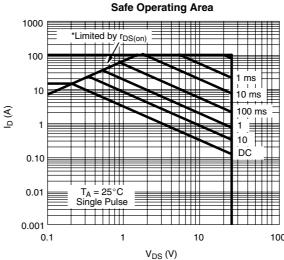
#### TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)









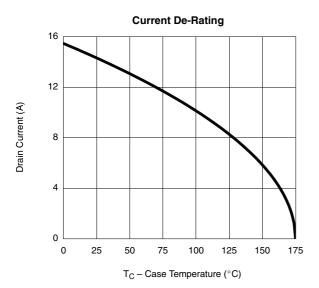


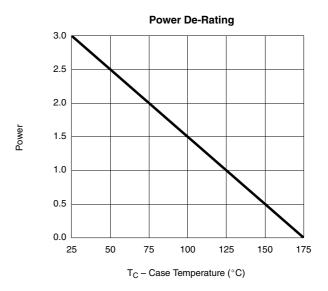
 $^\star V_{GS} > \mbox{minimum} \ V_{GS}$  at which  $\mbox{r}_{DS(on)}$  is specified

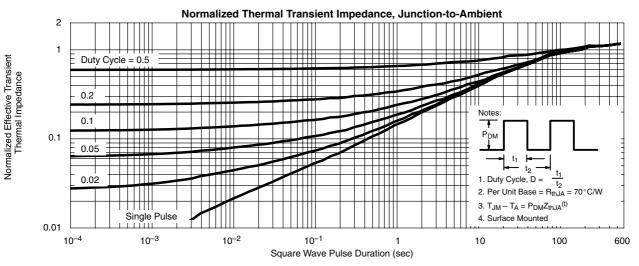
4/7



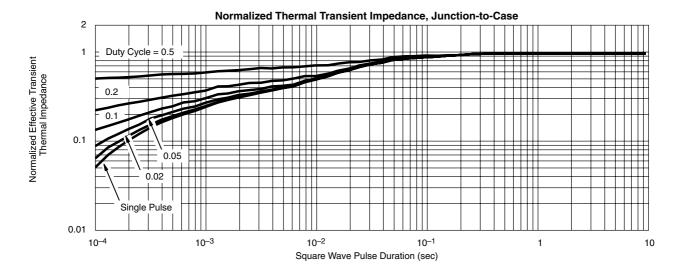
#### TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)







### TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)





### **Disclaimer**

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

freestyle Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on it s or their behalf (collectively, "freestyle"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

freestyle makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vi shay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain type s of applications are based on freestyle's knowledge of typical requirements that are often placed on freestyle products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specification s may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify freestyle's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, freestyle products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the freestyle product could result in personal injury or death. Customers using or selling freestyle products not expressly indicated for use in such applications do so at their own risk and agree to fully indemnify and hold freestyle and its distributors harmless from and against an y and all claims, liabilities, expenses and damages arising or resulting in connection with such use or sale, including attorneys fees, even if such claim alleges that Vis hay

### **Material Category Policy**

freestyle Intertechnology, Inc. hereby certi fies that all its products that are id entified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwis e specified as non-compliant.

Please note that some freestyle documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002 /95/EC conform to Directive 2011/65/EU.